

Notice of References Cited	Application/Control No. 10/669,045	Applicant(s)/Patent Under Reexamination SADOVNIKOV, ALEXEI	
	Examiner Jesse A. Fenty	Art Unit 2815	Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-5,793,067	08-1998	Miura et al.	257/183
	B	US-5,981,985	11-1999	Yang et al.	257/198
	C	US-6,049,098	04-2000	Sato, Fumihiko	257/198
	D	US-5,404,028	04-1995	Metzger et al.	257/15
	E	US-5,508,553	04-1996	Nakamura et al.	257/576
	F	US-5,494,836	02-1996	Imai, Kiyotaka	438/312
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	King et al., Very Low Cost Graded SiGe Base Bipolar Transistors for a High Performance Modular BiCMOS Process, 1999, IEDM 99, pp. 565-568.
	V	
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.